

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S25	2	(neutron adj detector) and (insulat\$5 with (silicon adj nitride))	US-PGPUB; USPAT; USOCR	OR	OFF	2005/10/04 14:24
S34	2	((Silicon adj nitride) with barrier) and (neutron same(detector or sensor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:14
S35	11	((Silicon adj nitride) with barrier) and (neutron and (detector or sensor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:16
S36	36	((Silicon adj nitride) with barrier) and radiation adj (detector or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:16
S37	342	((Silicon adj nitride) with (barrier adj layer) and (detector or sensor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:24
S38	2004	((Silicon adj nitride) with ((barrier adj layer) or (passivation))and (detector or sensor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:25
S39	3	((Neutron and (Silicon adj nitride)) with ((barrier adj layer) or (passivation))and (detector or sensor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 16:33
S40	214	((Neutron and (detector or sensor)) and ((barrier adj layer) or (passivation)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 17:43
S41	8	((Neutron adj (detector or sensor)) and (barrier adj layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 17:29
S42	140	(Neutron and (detector or sensor)) and (((barrier adj layer) or (passivation) with diffusion ))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 17:46

S43	12	(Neutron and (detector or sensor)) and (((barrier adj layer) or (passivation)) with diffusion )	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 17:51
S45	4	passivation and diffusion and (neutron adj detectors)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 18:04
S51	211	barrier with neutron	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 13:08
S52	22	(barrier with neutron) and detector and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:01
S55	223	barrier and (silicon adj nitride) and neutron	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:08
S56	52	(barrier with diffusion) and (silicon adj nitride) and neutron	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:19
S57	1070	(barrier with diffusion) and (silicon adj nitride) and (RAM or SRAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:20
S58	310	((barrier with diffusion) same (silicon adj nitride)) and (RAM or SRAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:20
S59	165	((barrier with diffusion) with (silicon adj nitride)) and (RAM or SRAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:20
S60	9	((barrier with diffusion) with (silicon adj nitride)) and (RAM or SRAM) and (detector or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:21

S61	157	((barrier with diffusion) with (silicon adj nitride)) and (RAM or SRAM) and semiconductor .	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:33
S62	1	((barrier with diffusion) with ((silicon adj nitride) or SiN) and (RAM or SRAM or cell) and semiconductor) and neutron	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:34
S63	1	((barrier same diffusion) with ((silicon adj nitride) or SiN) and (RAM or SRAM or cell) and semiconductor) and neutron	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:34
S66	2	(barrier adj layer) and (neutron adj (detector or sensor)) and ((Silicon adj nitride) or SiN)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/05 14:41